P4SMA Series



Vishay General Semiconductor

Surface Mount TRANSZORB[®] **Transient Voltage Suppressors**



DO-214AC (SMA)

PRIMARY CHARACTERISTICS						
V _{WM}	6.4 V to 459 V					
V _{BR} (uni-directional)	6.8 V to 540 V					
V _{BR} (bi-directional)	6.8 V to 220 V					
P _{PPM}	400 W, 300 W					
PD	3.3 W					
I _{FSM} (uni-directional only)	40 A					
T _J max.	150 °C					
Polarity	Uni-directional, bi-directional					
Package	DO-214AC (SMA)					

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional devices use CA suffix (e.g. P4SMA10CA). Electrical characteristics apply in both directions.

FEATURES

- Low profile package
- Ideal for automated placement
- · Glass passivated chip junction
- Available in uni-directional and bi-directional
- 400 W peak pulse power capability with a 10/1000 µs waveform, repetitive rate (duty cycle): 0.01 % (300 W above 91 V)



- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

MECHANICAL DATA

Case: DO-214AC (SMA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant and industrial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: For uni-directional types the band denotes cathode end, no marking on bi-directional types

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Peak power dissipation with a 10/1000 μs waveform $^{(1)(2)}$ (fig. 1)	P _{PPM}	400	W				
Peak pulse current with a 10/1000 μs waveform $^{(1)}$ (fig. 3)	I _{PPM}	See next table	А				
Power dissipation on infinite heatsink at $T_A = 50 \ ^\circ C$	PD	3.3	W				
Peak forward surge current 8.3 ms single half sine-wave uni-directional only $^{(2)}$	I _{FSM}	40	А				
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150	°C				

Notes

⁽¹⁾ Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2. Rating is 300 W above 91 V

⁽²⁾ Mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pads to each terminal

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P4SMA Series



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PART NUMBER	MAR	VICE KING DE	VOLT V _{BR} A	(DOWN FAGE TI _T ⁽¹⁾ V)	TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM} I _D ⁽⁴⁾	MAXIMUM PEAK PULSE CURRENT I _{PPM} ⁽²⁾	MAXIMUM CLAMPING VOLTAGE AT I _{PPM}	MAXIMUM TEMPERATURE COEFFICIENT OF V _{BR}
	UNI	BI	MIN.	MAX.	(iii/y	(•)	(μA)	(A)	V _C (V)	(%/°C)
P4SMA6.8A	6V8A	6V8C	6.45	7.14	10	5.80	1000	38.1	10.5	0.057
P4SMA7.5A	7V5A	7V5C	7.13	7.88	10	6.40	500	35.4	11.3	0.061
P4SMA8.2A	8V2A	8V2C	7.79	8.61	10	7.02	200	33.1	12.1	0.065
P4SMA9.1A	9V1A	9V1C	8.65	9.55	1.0	7.78	50	29.9	13.4	0.068
P4SMA10A	10A	10C	9.5	10.5	1.0	8.55	10	27.6	14.5	0.073
P4SMA11A	11A	11C	10.5	11.6	1.0	9.40	5.0	25.6	15.6	0.075
P4SMA12A	12A	12C	11.4	12.6	1.0	10.2	1.0	24.0	16.7	0.078
P4SMA13A	13A	13C	12.4	13.7	1.0	11.1	1.0	22.0	18.2	0.081
P4SMA15A	15A	15C	14.3	15.8	1.0	12.8	1.0	18.9	21.2	0.084
P4SMA16A	16A	16C	15.2	16.8	1.0	13.6	1.0	17.8	22.5	0.086
P4SMA18A	18A	18C	17.1	18.9	1.0	15.3	1.0	15.9	25.2	0.089
P4SMA20A	20A	20C	19.0	21.0	1.0	17.1	1.0	14.4	27.7	0.090
P4SMA22A	22A	22C	20.9	23.1	1.0	18.8	1.0	13.1	30.6	0.092
P4SMA24A	24A	24C	22.8	25.2	1.0	20.5	1.0	12.0	33.2	0.090
P4SMA27A	27A	27C	25.7	28.4	1.0	23.1	1.0	10.7	37.5	0.096
P4SMA30A	30A	30C	28.5	31.5	1.0	25.6	1.0	9.7	41.4	0.097
P4SMA33A	33A	33C	31.4	34.7	1.0	28.2	1.0	8.8	45.7	0.098
P4SMA36A	36A	36C	34.2	37.8	1.0	30.8	1.0	8.0	49.9	0.099
P4SMA39A	39A	39C	37.1	41.0	1.0	33.3	1.0	7.4	53.9	0.100
P4SMA43A	43A	43C	40.9	45.2	1.0	36.8	1.0	6.7	59.3	0.100
P4SMA47A	47A	400 47C	44.7	49.4	1.0	40.2	1.0	6.2	64.8	0.101
P4SMA51A	51A	51C	48.5	53.6	1.0	43.6	1.0	5.7	70.1	0.101
P4SMA56A	56A	56C	53.2	58.8	1.0	47.8	1.0	5.2	77.0	0.102
P4SMA62A	62A	62C	58.9	65.1	1.0	53.0	1.0	4.7	85.0	0.103
P4SMA68A	68A	68C	64.6	71.4	1.0	58.1	1.0	4.7	92.0	0.104
P4SMA00A P4SMA75A	75A	75C	71.3	78.8	1.0	64.1	1.0	3.9	104	0.105
P4SMA75A P4SMA82A	82A	82C		86.1	-				-	
P4SMA02A P4SMA01A	02A 91A	820 91C	77.9 86.5	95.5	1.0 1.0	70.1	1.0 1.0	3.5 3.2	113 125	0.105
	-					-	-	-	-	0.106
P4SMA100A	100A	100C	95.0	105	1.0	85.5	1.0	2.2	137	0.106
P4SMA110A P4SMA120A	110A	110C	105	116	1.0	94.0	1.0	2.0	152	0.107
	120A	120C	114	126	1.0	102	1.0	1.8	165	0.107
P4SMA130A	130A	130C	124	137	1.0	111	1.0	1.7	179	0.107
P4SMA150A	150A	150C	143	158	1.0	128	1.0	1.4	207	0.106
P4SMA160A	160A	160C	152	168	1.0	136	1.0	1.4	219	0.108
P4SMA170A	170A		162	179	1.0	145	1.0	1.3	234	0.108
P4SMA180A	180A	180C	171	189	1.0	154	1.0	1.2	246	0.108
P4SMA200A	200A	200C	190	210	1.0	171	1.0	1.1	274	0.108
P4SMA220A	220A	220C	209	231	1.0	185	1.0	0.9	328	0.108
P4SMA250A	250A	-	237	263	1.0	214	1.0	0.87	344	0.110
P4SMA300A	300A	-	285	315	1.0	256	1.0	0.73	414	0.110
P4SMA350A	350A	-	333	368	1.0	300	1.0	0.62	482	0.110
P4SMA400A	400A	-	380	420	1.0	342	1.0	0.55	548	0.110
P4SMA440A	440A	-	418	462	1.0	376	1.0	0.50	602	0.110
P4SMA480A	480A	-	456	504	1.0	408	1.0	0.46	658	0.110
P4SMA510A	510A	-	485	535	1.0	434	1.0	0.43	698	0.110
P4SMA540A	540A	-	513	567	1.0	459	1.0	0.41	740	0.110

Notes

⁽¹⁾ Pulse test: $t_p \le 50 \text{ ms}$

⁽²⁾ Surge current waveform per fig. 3 and derate per fig. 2

⁽³⁾ All terms and symbols are consistent with ANSI/IEEE CA62.35

 $^{(4)}$ For bi-directional types with V_R of 10 V and less, the I_D limit is doubled

⁽⁵⁾ $V_F = 3.5$ V at $I_F = 25$ A (uni-directional only)

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance, junction to ambient air ⁽¹⁾	$R_{ ext{ heta}JA}$	120	°C/W			
Typical thermal resistance, junction to lead						

Note

⁽¹⁾ Mounted on minimum recommended pad layout

ORDERING INFORMATION (Example)								
PREFERRED P/N		VOLTAGE RANGE (V)		PACKAGE	BASE	DELIVERY MODE		
	(g)	UNI -	BI -	CODE	QUANTITY			
P4SMA6.8A-E3/61	0.064	6.8 to 540	6.8 to 220	61	1800	7" diameter plastic tape and reel		
P4SMA6.8A-E3/5A	0.064	6.8 to 540	6.8 to 220	5A	7500	13" diameter plastic tape and reel		
P4SMA250AHE3_A/H (1)	0.064	250 to 540	-	Н	1800	7" diameter plastic tape and reel		
P4SMA250AHE3_A/I (1)	0.064	250 to 540	-	I	7500	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

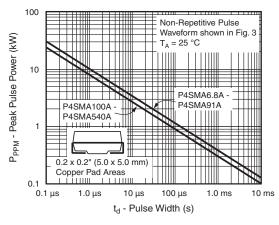


Fig. 1 - Peak Pulse Power Rating Curve

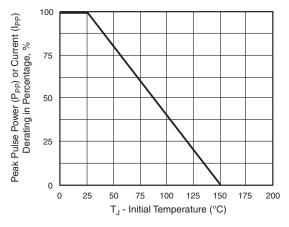
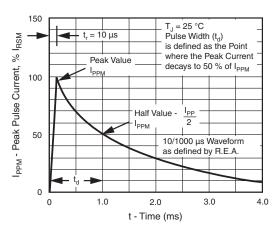


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature



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Fig. 3 - Pulse Waveform

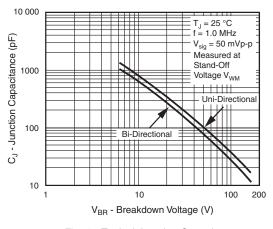


Fig. 4 - Typical Junction Capacitance

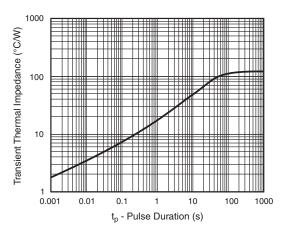


Fig. 5 - Typical Transient Thermal Impedance

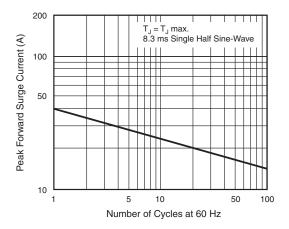


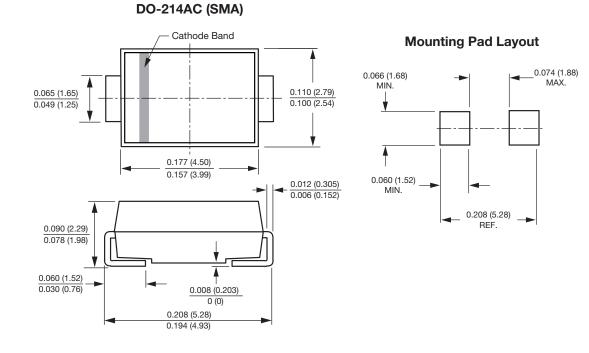
Fig. 6 - Maximum Non-Repetitive Forward Surge Current Uni-Directional Use Only

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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